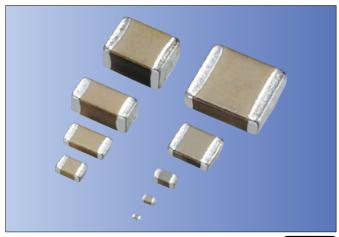
Multilayer Ceramic Chip Capacitors



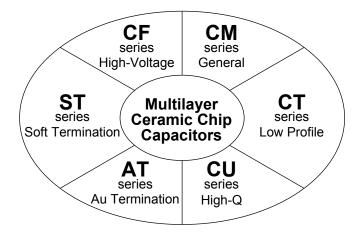
Kyocera's series of Multilayer Ceramic Chip Capacitors are designed to meet a wide variety of needs. We offer a complete range of products for both general and specialized applications, including CM series for general-purpose, CT series for low profile, CU series for Hi-Q, AT series for Au termination, ST series for soft termination, and CF series for high-voltage.

Features

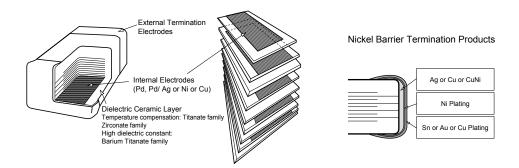
- We have a network worldwide in order to supply our global customer bases quickly and efficiently and to maintain our reputation as one of the highest-volume producers in the industry.
- All our products are highly reliable due to their monolithic structure of high-purity and superfine uniform ceramics and their integral internal electrodes.
- By combining superior manufacturing technology and materials with high dielectric constants, we produce extremely compact components with exceptional specifications.
- Our stringent quality control in every phase of production from material procurement to shipping ensures consistent manufacturing and super quality.
- Kyocera components are available in a wide choice of dimensions, temperature characteristics, rated voltages, and terminations to meet specific configurational requirements.







Structure



Tape and Reel



Please contact your local AVX, Kyocera sales office or distributor for specifications not covered in this catalog

Our products are continually being improved. As a result, the capacitance range of each series is subject to change without notice. Please contact an sales representative to confirm compatibility with your application.

Multilayer Ceramic Chip Capacitors



Kyocera Ceramic Chip Capacitors are available for different applications as classified below:

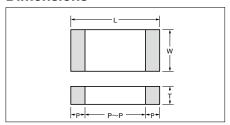
Series	Dielectric Options	Typical Applications	Features	Terminations	Available Size	
СМ	C0G (NP0) X5R X7R *X6S X7S	General purpose	Wide cap range	Nickel barrier/ Tin	01005, 0201, 0402 0603, 0805, 1206 1210, 1812	
СТ	X5R X7R	Module / Memory card	Low profile	Nickel barrier/ Tin	0201, 0402, 0603 0805, 1206, 1210	
CU	COG (NP0)	Power amplifier	High-Q	Nickel barrier/ Tin	01005	
AT	X5R X7R	Optical communications	Au termination	Nickel barrier/ Au	0201, 0402	
ST	X5R X7R X7S	PCB with severe bending conditions	Soft termination	Nickel barrier/ Tin (Soft Termination)	0201, 0402	
CF	C0G (NP0) X7R	High voltage & Power circuits	High voltage 250Vdc, 630Vdc 1000Vdc, 2000Vdc 3000Vdc, 4000Vdc	Nickel barrier/ Tin	0805, 1206, 1210 1808, 1812, 2208 2220	

^{*} Option
* Negative temperature coefficient dielectric types are available on request.

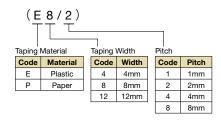
Multilayer Ceramic Chip Capacitors



Dimensions



%Packaging Code



Dimensions and Packaging Quantities

Size	Co		Dimension		\A/	Dimensions (m		Dimov	D to D mir	Maximum qua	
	JIS	EIA	Code		W	T	P min.	P max.	P to P min.	φ 180 Reel* 40kp (E4/1)	φ330 Reel*
02	0402	01005	Α	0.4±0.02	0.2±0.02	0.2±0.02	0.07	0.14	0.13	20kp (P8/2)	80kp (P8/2)
			Α			0.22 max.				30kp (P8/1)	150kp (P8/1)
				0.6±0.03	0.3±0.03	U.ZZ IIIdx.	0.10	0.20	0.20	15kp (P8/2)	50kp (P8/2)
			В			0.3±0.03				30kp (P8/1) 15kp (P8/2)	150kp (P8/1) 50kp (P8/2)
03	0603	0201	С	0.6±0.05	0.240.05	0.3±0.05	0.13	0.00	0.19	30kp (P8/1) 15kp (P8/2)	150kp (P8/1)
				0.6±0.05	0.3±0.05		0.13	0.23	0.19	15kp (P8/2)	50kp (P8/2)
			D E	0.6±0.09	0.3±0.09	0.3±0.09 0.25 max.	0.13	0.23	0.19	15kp (P8/2) 15kp (P8/2)	-
		ŀ	F	0.6±0.10	0.3±0.10	0.25 max. 0.3±0.10	0.13	0.23	0.19	15kp (P8/2)	-
			A		3.0 3	0.22 max.				20kp (P8/1)	100kp (P8/1)
						U.ZZ IIIdx.	_			10kp (P8/2)	50kp (P8/2)
			В			0.25 max.				20kp (P8/1) 10kp (P8/2)	100kp (P8/1) 50kp (P8/2)
		ľ	С	1 0+0 05	0.5+0.05	0.22 may				20kp (P8/1)	100kp (P8/1)
				1.0±0.05	0.5±0.05	0.33 max.				10kp (P8/2)	50kp (P8/2)
			D			0.35 max.				20kp (P8/1) 10kp (P8/2)	100kp (P8/1) 50kp (P8/2)
		ŀ	_			0.510.05	-			20kp (P8/1)	100kp (P8/1)
05	1005	0402	E			0.5±0.05	0.15	0.35	0.30	10kp (P8/2)	50kp (P8/2)
00	1000	0402	F	1.0±0.07	0.5±0.07	0.5±0.07	0.15	0.00	0.00	20kp (P8/1)	50kp (P8/2)
		ŀ	_				-			10kp (P8/2) 20kp (P8/1)	100kp (P8/1)
			G	1.0+0.10	0.5+0.10	0.35 max.				10kp (P8/2)	50kp (P8/2)
			н	1.0±0.10	0.5±0.10	0.5±0.10	1			20kp (P8/1)	50kp (P8/2)
										10kp (P8/2) 20kp (P8/1)	
			J	1.0±0.15	0.5±0.15	0.5±0.15				10kp (P8/2)	50kp (P8/2)
		l	K	1.0±0.20	0.5±0.20	0.33 max.	j			10kp (P8/2)	-
			L	1.0±0.20	0.5±0.20	0.5±0.20				10kp (P8/2)	- 10l (D0 (4)
			Α	1.6±0.10	0.8±0.10	0.55 max.	-			4kp (P8/4) 8kp (P8/2)	10kp (P8/4) 20kp (P8/2)
			В	1.0=0.10	0.0=0.10	0.8±0.10				4kp (P8/4)	10kp (P8/4)
			С			0.55 max.]			8kp (P8/2)	20kp (P8/2)
105	1608	0603		1.6±0.15	0.8±0.15	0.00	0.20	0.60	0.50	4kp (P8/4) 8kp (P8/2)	10kp (P8/4) 20kp (P8/2)
			D			0.8±0.15				4kp (P8/4)	10kp (P8/4)
		l	Е			0.55 max.				8kp (P8/2)	20kp (P8/2)
			F	1.6±0.20	0.8±0.20					4kp (P8/4)	10kp (P8/4)
			A			0.8±0.20 0.55 max.				* 4kp (P8/4)	- 10kp (P8/4)
			В			0.95 max.	j			4kp (P8/4) 4kp (E8/4)	10kp (P8/4) 10kp (E8/4)
			C	0.010.40	4.0510.40	1.00 max.				4kp (E8/4)	10kp (E8/4)
		ŀ	D E	2.0±0.10	1.25±0.10	0.6±0.1 0.85±0.10				4kp (P8/4) 4kp (P8/4)	10kp (P8/4) 10kp (P8/4)
21	2012	0805	F			1.05±0.10	0.20	0.75	0.70	3kp (E8/4)	10kp (E8/4)
21	2012	0005	G			1.25±0.10	0.20	0.75	0.70	3kp (E8/4)	10kp (E8/4)
		1	H J	2.0±0.15	1.25±0.15	0.55 max. 0.95 max.	-			4kp (P8/4) 4kp (P8/4)	10kp (P8/4) 10kp (P8/4)
		ŀ	K	2.0±0.10	1.25±0.15	1.25±0.15	1			3kp (E8/4)	10kp (E8/4)
			L	2.0±0.20	1.25±0.20	0.95 max.]			4kp (P8/4)	10kp (P8/4)
			M	2.0-0.20	1120-0120	1.25±0.20 0.95 max.				3kp (E8/4) 4kp (P8/4)	10kp (E8/4) 10kp (P8/4)
		ŀ	A B			1.00 max.	-			4kp (F8/4) 4kp (E8/4)	10kp (F8/4)
		l	С	3.2±0.20	1.6±0.15	1.15±0.10]			3kp (E8/4)	10kp (E8/4)
246	2016	1006	D			1.25±0.10	0.30	0.85	1.40	3kp (E8/4)	10kp (E8/4)
316	3216	1206	E F			1.6±0.15 0.95 max.	-			2.5kp (E8/4) 4kp (P8/4)	5kp (E8/4) 10kp (P8/4)
			G	3.2±0.20	1.6±0.20	1.00 max.	-			4kp (E8/4)	10kp (E8/4)
			H	0.010.00	10/00	1.6±0.20	0.00	0.55	1.00	2.5kp (E8/4)	5kp (E8/4)
			J A	3.2±0.30	1.6±0.30	1.6±0.30 1.00 max.	0.30	0.85	1.90	2kp (E8/4) 4kp (E8/4)	- 10kp (E8/4)
		}	В			1.40 max.				3kp (E8/4)	10kp (E8/4)
			С			1.60 max.]			2.5kp (E8/4)	5kp (E8/4)
32	3225	1210	D E	3.2±0.30	2.5±0.20	1.6±0.15 2.20 max.	0.30	1.00	1.40	2.5kp (E8/4) 2kp (E8/4)	5kp (E8/4)
		}	F			2.20 max. 2.0±0.2	1			2kp (E8/4) 2kp (E8/4)	5kp (E8/4) 5kp (E8/4)
			G			2.5±0.2				1kp (E8/4)	4kp (E8/4)
42	4520	1808	A	4.5±0.20	2.0±0.20	1.6 max.	0.15	0.85	2.60	2kp (E12/4)	-
			B A			2.2 max. 2.0 max.				2kp (E12/4) 1kp (E12/8)	-
		ŀ	B			2.0±0.2				1kp (E12/8)	-
43	4532	1812	C 4.5±0.30		3.2±0.20	2.5 max.	0.30	1.10	2.00	0.5kp (E12/8)	-
			D E			2.5±0.2 2.8±0.2				0.5kp (E12/8) 0.5kp (E12/8)	-
52	5720	2208	A	5.7±0.40	2.0±0.20	2.8±0.2 2.2 max.	0.15	0.85	4.20	2kp (E12/4)	
			Α			2.0 max.				1kp (E12/8)	-
rr l	5750	2220	В	5.7±0.40	5.0±0.40	2.5 max.	0.30	1.40	2.50	0.5kp (E12/8)	-
55	0.00	1	С			2.8 max.	1		1	0.5kp (E12/8)	-

Multilayer Ceramic Chip Capacitors Ordering Information



SERIES CODE CM = General Purpose		ı		
CM = General Purpose				
CT = Low Profile CU = High-Q	AT = Au termination ST = Soft termination CF = High Voltage			
SIZE CODE ———				
SIZE EIA (JIS) 02 = 01005 (0402) 03 = 0201 (0603) 05 = 0402 (1005) 105 = 0603 (1608) 21 = 0805 (2012) 316 = 1206 (3216)	SIZE EIA (JIS) 32 = 1210 (3225) 42 = 1808 (4520) 43 = 1812 (4532) 52 = 2208 (5720) 55 = 2220 (5750)			
DIELECTRIC CODE				
CODE EIA CODE CG = C0G (NPO) X5R = X5R X7R = X7R Negative temperature coeffic	X7S = X7S X6S = X6S (Option) ient dielectric types are available on request.			
CAPACITANCE CODI	<u> </u>			
$0.1 \mu F = 104$	enotes decimal point, 1.5pF = 1R5 0.5pF = R50 100μF = 107			
TOLERANCE CODE				
B = $\pm 0.1 pF$ G	= ± 0.5 pF			
VOLTAGE CODE —				
04 = 4Vdc 100 06 = 6.3Vdc 250 10 = 10Vdc 630 16 = 16Vdc 25 = 25Vdc 35 = 35Vdc	= 100Vdc = 250Vdc = 630Vdc = 630Vdc = 630Vdc = 4000Vdc			
04 = 4Vdc 100 06 = 6.3Vdc 250 10 = 10Vdc 630 16 = 16Vdc 25 = 25Vdc 35 = 35Vdc 50 = 50Vdc	= 250Vdc = 630Vdc = 630Vdc = 2000 = 2000Vdc = 3000 = 3000Vdc = 4000Vdc			
04 = 4Vdc 100 06 = 6.3Vdc 250 10 = 10Vdc 630 16 = 16Vdc 25 = 25Vdc 35 = 35Vdc 50 = 50Vdc TERMINATION CODE	= 250Vdc = 630Vdc = 630Vdc = 2000 = 2000Vdc = 3000 = 3000Vdc = 4000Vdc	rier/ Cu	I Barrier/ Tin Termination)	
04 = 4Vdc 100 06 = 6.3Vdc 250 10 = 10Vdc 630 16 = 16Vdc	= 250Vdc 2000 = 2000Vdc = 630Vdc 3000 = 3000Vdc 4000 = 4000Vdc *G = Nickel Barrier/ Au Y = Nickel Barrier/ Au (option) G : AuSn solder and conductive adhesive.	rier/ Cu		

Above digits are used to track individual specification except for CT Series. Maximum thickness is indicated in CT Series.

EX. 125 \rightarrow 1.25mm max. 095 \rightarrow 0.95mm max.

Multilayer Ceramic Chip Capacitors Temperature Characteristics and Tolerance



Temperature Compensation Type

Code	ppm	ı/ °C	Temperature Range
CG	0	±30	−55 to 125°C
CH	U	±60	-33 10 123 0

Note: All parts of COG will be marked as "CG" but will conform to the above table.

High Dielectric Constant Type

EIA Dielectric	Temperature Range	∆C max.			
X5R	−55 to 85°C	±15%			
X7R	−55 to 125°C	±1 5 %			
X7S	−55 to 125°C	±22%			
*X6S	−55 to 105°C	±22%			

^{*} option

Available Tolerances

Dielectric materials, capacitance values and tolerances are available in the following combinations only:

EIA Dielectric	Tolerance	Capacitance
	*2 A = ±0.05pF	<0.5pF
	B = ±0.1pF	≤5pF
	C = ±0.25pF	*1 <10pF
COG	$D = \pm 0.50 pF$	< TOPF
	* ₂ G = ±2%	
	J = ±5%	≥10pF E12 Series
	$K = \pm 10\%$	E12 Series
*.	*2 J = ±5%	
*2 X6S X5R X7S X7R	K = ±10%	*3 E3 Series
7C 7	M = ±20%	

Note:

E Standard Number

L Standard Humber											
E3	E 6	E12	E24 (C	ption)							
	1.0	1.0	1.0	1.1							
1.0	1.0	1.2	1.2	1.3							
1.0	1.5	1.5	1.5	1.6							
	1.5	1.8	1.8	2.0							
	2.2	2.2	2.2	2.4							
2.2	2.2	2.7	2.7	3.0							
2.2	3.3	3.3	3.3	3.6							
	3.3	3.9	3.9	4.3							
	4.7	4.7	4.7	5.1							
4.7	4.7	5.6	5.6	6.2							
4.7	6.8	6.8	6.8	7.5							
	0.0	8.2	8.2	9.1							

Temperature coefficients are determined by calculation based on measurement at 20°C and 85°C.

^{*1} Nominal values below 10pF are available in the standard values of 0.5pF, 1.0pF, 1.5pF, 2.0pF, 3.0pF, 4.0pF, 5.0pF, 6.0pF, 7.0pF, 8.0pF, 9.0pF

^{*2} option

^{*3} E6 series is available on request.

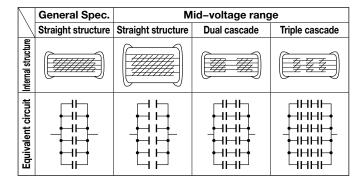
CF Series High Voltage Applications



[RoHS Compliant Products]

Features

Perform less than 1 fit failure ratio by high voltage durability and high reliability which has optimized internal electrode structure based on designing of safety.



• Mid-voltage range (Straight structure)

Enough break-down voltage margin by taking suitable dielectric thickness for individual rated voltage.

• Mid-voltage range (Dual cascade structure)

Realize high voltage performance by series connection of two multilayer capacitor units in a MLCC to divide applied voltage into two. High durability to surging voltage is guaranteed.

• Mid-voltage range (Triple cascade structure)

Realize high voltage performance by series connection of three multilayer capacitor units in a MLCC to divide applied voltage into three. Excellent safety is secured.

The multi cascade structure is a safety design to avoid short circuit failure.

Applications

- Camera/ Strobe circuit, Surge Killing, Trigger Circuit
- LCD Back light Inverter, Ballast Capacitor
- Power Circuit/ DC-DC Converter, Snubber Circuit

Special specification for individual application

A suitable guaranteeing specification will be examined to satisfy customer's application, such as for AC voltage application.

* Information of usage condition will be necessary to be examined.

Custom specification will be available according to your request. Ex. Specification relating to AC voltage.

* In-use condition shall be confirmed.

Temperature Compensation Dielectric

e ics	*			CF316 (1206)		10)		(1808)		(18	(2208)	
.00	C∆*		C∆*		C	Δ*		C∆*		C∆*		C∆*
dc) pF)	250	630	1000	2000	1000	2000	1000	2000	3000	1000	3000	4000
0.5												
3.0												
4.0												
	D	С	С	С								
							Α —	A	_ A _			
9.0												
10												Α
22												A
47				E		D		В	В			
00		D	Ď				В					
	G				Ē						С	
										С		
1 2 2 0 2 7 0 0	0F) 0.5 1.0 1.5 2.0 3.0 4.0 5.0 6.0 7.0 8.0 9.0 10 222 47 00 20 70	250 0.5 1.0 1.5 2.0 3.0 4.0 5.0 6.0 7.0 8.0 9.0 10 10 222 47 000 E	250 630 0.5 1.0 1.5 2.0 3.0 4.0 5.0 6.0 7.0 8.0 9.0 10 222 477 00 E D G 770 00	250 630 1000 0.5 1.0 1.5 2.0 3.0 4.0 5.0 6.0 D C C C 7.0 8.0 9.0 10 E D D D D D D D D D D D D D D D D D D	250 630 1000 2000 0.5 1.0 1.5 2.0 3.0 4.0 5.0 6.0 D C C C C 7.0 8.0 9.0 10 E D D E	0.5 250 630 1000 2000 1000	0.5 250 630 1000 2000 1000 2000 1000 2000 1000 2000 1000 2000 1000 2000 1000 2000 1000 2000 1000	0.5 250 630 1000 2000 1000 2000 1000	0.5	0.5	0.5	0.5

< Standard Capacitance Value >

E3 Series

Please contact for capacitance value other than standard.

* : CG,CH

Alphabets in capacitance chart denote dimensions. Please refer to the below table for detail.

Size	Size	Di	Dimension (mm)								
Size	Code	L	W	T							
	D	2.0±0.10	1.25±0.10	0.6±0.10							
21	E	2.0±0.10	1.25±0.10	0.85±0.10							
	G	2.0±0.10	1.25±0.10	1.25±0.10							
	С	3.2±0.20	1.6±0.15	1.15±0.10							
316	D	3.2±0.20	1.6±0.15	1.25±0.10							
	E	3.2±0.20	1.6±0.15	1.6±0.15							

Size	Size	Di	mension (m	m)
Size	Code	L	W	Т
32	D	3.2±0.30	2.5±0.20	1.6±0.15
32	F	3.2±0.30	2.5±0.20	2.0±0.2
42	Α	4.5±0.20	2.0±0.20	1.6 max.
42	В	4.5±0.20	2.0±0.20	2.2 max.
43	С	4.5±0.30	3.2±0.20	2.5 max.
52	Α	5.7±0.40	2.0±0.20	2.2 max.

Tolerance Code

To	emperature Cor	npensation				
ode	Tolerance	Capacitance				
С	±0.25pF	C<10pF				
D	±0.5pF	C<10pr				
J	±5%	C>10pE				
K	±10%	C≥10pF				
	ode C	C ±0.25pF D ±0.5pF J ±5%				

CF Series High Voltage Applications



[RoHS Compliant Products]

X7R Dielectric

_	Size Code)	CF21 (0805)		CF316 (1206)			CF32 (1210)		_	-42 308)			43 12)			CF (22	55 20)	
	/oltage (Vdc) itance (pF)	250	250	630	1000	250	630	1000	1000	2000	250	630	1000	2000	250	630	1000	2000
102	220 470 1000	E1		C1	C1 D1					B1								
103	2200 4700 10000	F1 G1	C1	D1	E1			D1	B1					C1				A1 C1
104	22000 47000 100000	g.	E1	E1		F1	D1 F1				A 1	A1 C1	C1			A 1	A1 B1	
105	220000 470000 1000000										C1				A1	C1		

<Standard Capacitance Value>

E3 Series

Please contact for capacitance value other than standard.

Two digits alphanumerics in capacitance chart denote dimensions and $\tan \delta$. Please refer to the below table for detail.

(Example)
In case of "E1" for CF21;
L : 2.0±0.1mm
W : 1.25±0.1mm
T : 0.85±0.1mm Tan δ : 2.5% max.

Size	Size	Di	mension (m	ension (mm)		
Size	Code	L	W	T		
	E	2.0±0.10	1.25±0.10	0.85±0.10		
21	F	2.0±0.10	1.25±0.10	1.05±0.10		
	G	2.0±0.10	1.25±0.10	1.25±0.10		
	С	3.2±0.20	1.6±0.15	1.15±0.10		
316	D	3.2±0.20	1.6±0.15	1.25±0.10		
	E	3.2±0.20	1.6±0.15	1.6±0.15		
32	D	3.2±0.30	2.5±0.20	1.6±0.15		
32	F	3.2±0.30	2.5±0.20	2.0±0.2		

Size	Size	Dimension (mm)					
Code		L	W	T			
42	В	4.5±0.20	2.0±0.20	2.2 max.			
43	Α	4.5±0.30	3.2±0.20	2.0 max.			
43	С	4.5±0.30	3.2±0.20	2.5 max.			
	Α	5.7±0.40	5.0±0.40	2.0 max.			
55	В	5.7±0.40	5.0±0.40	2.5 max.			
	С	5.7±0.40	5.0±0.40	2.8 max.			

Tan δ Code	Tan δ
1	2.5% max.

Multilayer Ceramic Chip Capacitors Test Conditions and Standards



Test Conditions and Specifications for Temperature Compensation Type (C△ Characteristics) CM/ CU/ CF Series

Test	Items		Test Condition	าร	Specifications	
Capacitance V	/alue (C)	Capacitan	ce Frequency	Volt	Within tolerance	
Q		C≤1000pl C>1000pl	1MHz±10%	0.5 to 5Vrms	C≥30pF: Q≥1000 C<30pF: Q≥400+20C	
Insulation Resistance (IR)		Measured after the rated voltage is applied for 1 minute at room ambient. For the rated voltage of over 630V, apply 500V for 1 minute at room ambient. The charge and discharge current of the capacitor must not exceed 50mA.			Over 10000M Ω or 500M Ω • μ F, whichever is less	
Dielectric Resistance		Apply 3 times of the rated voltage for 1 to 5 seconds. Apply 1.5 times when the rated voltage is 250V or over. Apply 1.2 times when the rated voltage is 630V or over. The charge and discharge current of the capacitor must not exceed 50mA.			No problem observed	
Appearance		Microscope			No problem observed	
Termination St	trength		ard force of 500g (ple. Apply 2N for 0		No problem observed	
Bending Stren	gth	Glass epoxy Potime 10 second	CB: Fulcrum spacin ds.	g: 90mm, duration	No significant damage at 1mm bent	
Vibration	Appearance		uency: 10 to 55 (Hz	<u>z</u>)	No problem observed	
Test	ΔC	Amplitude: 1.5 Sweeping con	omm dition: 10→55→10	Hz/ 1 minute in X	Within Tolerance	
	Q	Y and Z Directions: 2 h	nours each, 6 hours	s total.	C≥30pF: Q≥1000 C<30pF: Q≥400+20C	
Soldering	Appearance		ple in 260°C±5°C s		No problem observed	
Heat Resistance	ΔC	after 24±2 hou	olace in room ambi ırs.	ient, and measure	Within ±2.5% or ±0.25pF, whichever is larger	
	Q	(Pre-heating conditions)			C≥30pF: Q≥1000	
	ID.	Order	Temperature	Time	C<30pF: Q≥400+20C	
	Withstanding Voltage	1 80 to 100°C 2 minutes 2 150 to 200°C 2 minutes The charge and discharge current of the capacitor must not exceed 50mA for IR and withstanding voltage measurement.		2 minutes	Over $10000M\Omega$ or $500M\Omega$ • μF whichever is less Resist without problem	
Solderablity		Sn-3Ag-0.5Cu 245±5°C 3±0.5 sec. Sn63 Solder 235±5°C 2±0.5 sec.			Solder coverage : 90% min.	
Temperature	Appearance	(Cycle)			No problem observed	
Cycle	ΔC	Room temper	ature (3min.)→		Within ±2.5% or ±0.25pF, whichever is larger	
	Q	Lowest operation temperature (30min.)→ Room temperature (3min.)→			C≥30pF: Q≥1000 C<30pF: Q≥400+20C	
	IR	Highest operation temperature(30min.)		Umin.)	Over $10000M\Omega$ or $500M\Omega$ • μF , whichever is less	
	Withstanding Voltage	After 5 cycles, measure after 24±2 hours. The charge and discharge current of the capacitor must not exceed 50mA for IR and withstanding voltage measurement.		nt of the capacitor	Resist without problem	
Load	Appearance		rated voltage for 5		No problem observed	
Humidity Test	ΔC		on at 40°C±2°C, hu	•	Within ±7.5% or ±0.75pF, whichever is larger	
(Except CF Series)		room tempera	ture before measu d discharge currer	rement.	C≥30pF : Q≥200	
	IR	must not exce	ed 50mA for IR me	easurement.	Over $500M\Omega$ or $25M\Omega$ • μF , whichever is less	
High-	Appearance	After applying	twice the rated vo	Itage at the	No problem observed.	
Temperature with Loading	ΔC	•	f 125±3°C for 1000		Within ±3% or ±0.3pF, whichever is larger	
Localing	Q	measure the sample after 24±2 hours. Apply 1.5 times when the rated voltage is 250V or over. Apply 1.2 times when the rated voltage is 630V or over. The charge and discharge current of the capacitor			0.40-5.05000.400	
	IR	must not exce	ed 50mA for IR me	easurement.	Over 1000MΩ or 50MΩ • μF, whichever is less	
loaco ack for indi	vidual specificatio	n for the betch	d range in presiden	o obort		

Please ask for individual specification for the hatched range in previous chart.

Multilayer Ceramic Chip Capacitors Test Conditions and Standards



Test Conditions and Specifications for High Dielectric Type (X7R) CF Series

Test	Test Items Test Conditions		Specifications	
Capacitance V	/alue (C)	Measure after heat trea	atment	Within tolerance
Tanδ (%)		Capacitance Frequency Volt C≤10μF 1kHz±10% 1.0±0.2Vrms		Within 2.5%
Insulation Resistance (IR)		Measured after the rated voltage is applied for 1 minute at room ambient. Measured after the 500V is applied for 1 minute at room ambient for the rated voltage over 630V. The charge and discharge current of the capacitor must not exceed 50mA.		Over 10000M Ω or 500M Ω • μ F, whichever is less Over 100M Ω • μ F for CF316X7R104/ 250V and CF55X7R224/ 630V
Dielectric Res	istance	Apply 1.5 times when th 250V or over, apply 1.2 t voltage is 630V or over f The charge and dischar capacitor must not exc	times when the rated for 1 to 5 seconds. urge current of the	No problem observed
Appearance		Microscope		No problem observed
Termination St	trength	Apply a sideward force PCB-mounted sample.		No problem observed
Bending Stren	gth	Glass epoxy PCB: Fulc duration time 10 secon		No significant damage at 1mm bent
Vibration Test	Appearance	Take the initial value aft Vibration frequency: 10		No problem observed
1621	ΔC	Amplitude: 1.5mm	, ,	Within tolerance
	Tanδ (%)	Sweeping condition: 10- in X, Y and Z Directions: 2 hours eac		Within tolerance
Soldering	Appearance	Take the initial value aft		No problem observed
Heat Resistance	ΔC	Soak the sample in 260 10±0.5 seconds and pla		Within ±7.5%
	Tanδ (%)	and measure after 24±2 (Pre-heating conditions		Within tolerance
	IR	Order Tempera 1 80 to 10	ature Time	Over 10000M Ω or 500M Ω • μ F, whichever is less Over 100M Ω • μ F for CF316X7R104/ 250V and CF55X7R224/ 630V
	Withstanding Voltage	2 150 to 20 The charge and discharge capacitor must not excuit with standing voltage m	harge current of the ceed 50mA for IR and	Resist without problem
Solderablity		Soaking condition Sn-3Ag-0.5Cu 245:	±5°C 3±0.5 sec. ±5°C 2±0.5 sec.	Solder coverage : 90% min.
Temperature Cycle	Appearance	Take the initial value aft (Cycle)	ter heat treatment.	No problem observed
Cycle	ΔC	Room temperature (3m		Within ±7.5%
	Tanδ (%)	Lowest operation temp Room temperature (3m		Within tolerance
	IR	Highest operation temp After 5 cycles, measure	perature(30min.) e after 24±2 hours.	Over 10000M Ω or 500M Ω • μ F, whichever is less Over 100M Ω • μ F for CF316X7R104/ 250V and CF55X7R224/ 630V
	Withstanding Voltage	The charge and discharge current of the capacitor must not exceed 50mA for IR and withstanding voltage measurement.		Resist without problem
High-	Appearance	Take the initial value after		No problem observed
Temperature with	ΔC		1000+12/ –0 hours,	Within ±12.5%
with Loading Tanδ (%) Tanδ (%) IR operation temperature for 1000+12/ –0 hours, then measure the sample after 24±2 hours. The applied voltage shall be; 1.5 times the rated voltage when the rated voltage is 250V. 1.2 times when the rated voltage is 630V or over. The charge and discharge current of the capacitor must not exceed 50mA for IR measurement.		200% max. of initial value $\label{eq:over1000M}$ Over 1000M\$\Omega\$ or 50M\$\Omega\$ • \$\mu\$F, whichever is less		
Pre-treat-	Heat	Keep specimen at 150)+0/ –10°C for 1 hour, l	leave specimen at room ambient for 24±2 hours.

Apply the same test condition for 1 hour, then leave the specimen at room ambient for 24 ± 2 hours.

ment

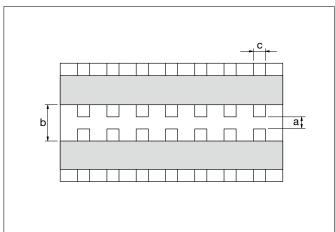
Voltage

Multilayer Ceramic Chip Capacitors Test Conditions and Standards



(Unit: mm)

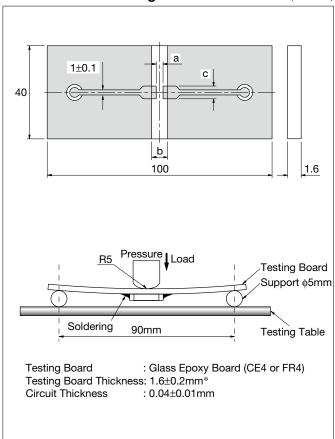
Substrate for Electrical Tests



Size (EIA Code)	а	b	С
02 (01005)	0.15	0.50	0.20
03 (0201)	0.26	0.92	0.32
05 (0402)	0.4	1.4	0.5
105 (0603)	1.0	3.0	1.2
21 (0805)	1.2	4.0	1.65
316 (1206)	2.2	5.0	2.0
32 (1210)	2.2	5.0	2.9
42 (1808)	3.5	7.0	3.7
43 (1812)	3.5	7.0	3.7
52 (2208)	4.5	8.0	5.6
55 (2220)	4.5	8.0	5.6

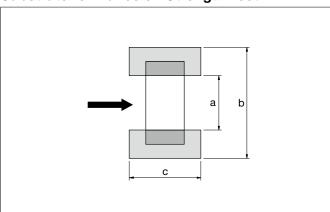
Substrate for Bending Test

(Unit: mm)



* 02, 03, 05 size 0.8±0.1mm

Substrate for Adhesion Strength Test

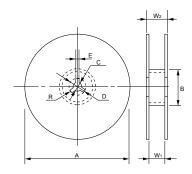


Multilayer Ceramic Chip Capacitors Packaging Options



Tape and Reel

• Reel



Reel

(Unit: mm)

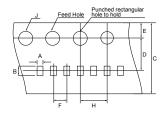
Code Reel	Α	В	С	D
7-inch Reel (CODE: T, H, Q)	180 +0 -2.0			
7-inch Reel (CODE: P)	178±2.0	φ60 min.	13±0.5	21±0.8
13-inch Reel (CODE: L, N, W)	330±2.0			
Code Reel	E	W 1	W ₂	R
	E	W ₁	W ₂	R
Reel 7-inch Reel	E 2.0±0.5			R

^{*} Carrier tape width 8mm.

For size 42 (1808) or over, Tape width 12mm and W1: 14 ± 1.5 , W2: 18.4mm max.

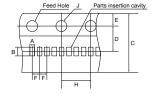
Carrier Tape

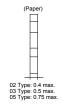
F = 1mm (02 Type)



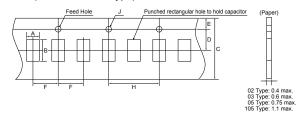


F = 1mm (02, 03, 05 Type)

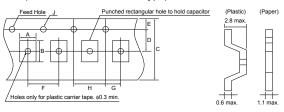




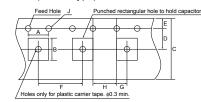
F = 2mm (02, 03, 05, 105 Type)



F = 4mm (105, 21, 316, 32, 42, 52 Type)



F = 8mm (43, 55 Type)





Carrier Tape (Unit: mm)

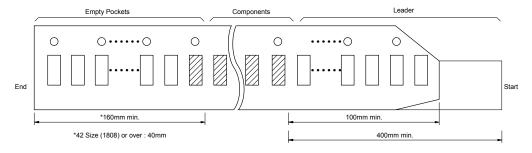
Size (EIA Code)	Α	В	С	D	E	F	G	Н	J	Carrier Tape
02 (01005)*	0.23±0.02	0.43±0.02	4.0±0.08	1.8±0.02	0.9±0.05	1.0±0.02	_	2.0±0.04	0.8±0.04	4mm, Plastic
02 (01005)	0.25±0.03	0.45±0.03	8.0±0.3	3.5±0.05	1.75±0.1	2.0±0.05	_	4.0±0.1	1.5+0.1/-0	8mm, Paper
03 (0201)*	0.37±0.03	0.67±0.03	8.0+0.3/-0.1	3.5±0.05	1.75±0.1	1.0±0.05	_	4.0±0.05	1.5+0.1/-0	8mm, Paper
03 (0201)	0.37±0.03	0.67±0.03	8.0±0.3	3.5±0.05	1.75±0.1	2.0±0.05	_	4.0±0.1	1.5+0.1/-0	8mm, Paper
05 (0402)*	0.65±0.1	1.15±0.1	8.0+0.3/-0.1	3.5±0.05	1.75±0.1	1.0±0.05		4.0±0.05	1.5+0.1/-0	8mm, Paper
03 (0402)	0.65±0.1	1.15±0.1	8.0±0.3	3.5±0.05	1.75±0.1	2.0±0.05	_	4.0±0.1	1.5+0.1/-0	8mm, Paper
105 (0603)	1.0±0.2	1.8±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.05	4.0±0.1	1.5+0.1/-0	8mm, Paper
21 (0805)	1.5±0.2	2.3±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.05	4.0±0.1	1.5+0.1/-0	8mm, Paper
21 (0003)	1.5±0.2	2.3±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.05	4.0±0.1	1.5+0.1/-0	8mm, Plastic
316 (1206)	2.0±0.2	3.6±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.05	4.0±0.1	1.5+0.1/-0	8mm, Paper
310 (1200)	2.0±0.2	3.6±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.05	4.0±0.1	1.5+0.1/-0	8mm, Plastic
32 (1210)	2.9±0.2	3.6±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.05	4.0±0.1	1.5+0.1/-0	8mm, Plastic
42 (1808)	2.4±0.2	4.9±0.2	12.0±0.3	5.5±0.05	1.75±0.1	4.0±0.1	2.0±0.05	4.0±0.1	1.5+0.1/-0	12mm, Plastic
43 (1812)	3.6±0.2	4.9±0.2	12.0±0.3	5.5±0.05	1.75±0.1	8.0±0.1	2.0±0.05	4.0±0.1	1.5+0.1/-0	12mm, Plastic
52 (2208)	2.4±0.2	6.0±0.2	12.0±0.3	5.5±0.05	1.75±0.1	4.0±0.1	2.0±0.05	4.0±0.1	1.5+0.1/-0	12mm, Plastic
55 (2220)	5.3±0.2	6.0±0.2	12.0±0.3	5.5±0.05	1.75±0.1	8.0±0.1	2.0±0.05	4.0±0.1	1.5+0.1/-0	12mm, Plastic

^{*} Option

Multilayer Ceramic Chip Capacitors Packaging Options



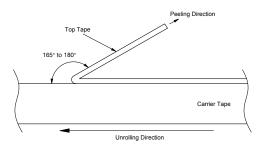
Detail of leader and trailer



Adhesive tape

- 1) The exfoliative strength when peeling off the top tape from the carrier tape by the method of the following figure shall be *0.1 to 0.7N. *02 Size: 0.1 to 0.5N
- 2) When the top tape is peeled off, the adhesive stays on the top tape.
- 3) Chip capacitors will be in a state free without being stuck on the thermal adhesive tape.

Exfoliating angle: 165 to 180 degrees to the carrier tape. Exfoliating speed: 300 mm/min.



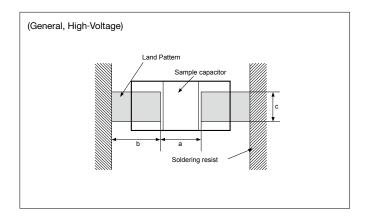
Multilayer Ceramic Chip Capacitors Surface Mounting Information



Dimensions for recommended typical land

Since the amount of solder (size of fillet) to be used has direct influence on the capacitor after mounting, the sufficient consideration is necessary.

When the amounts of solder is too much, the stress that a capacitor receives becomes larger. It may become the cause of a crack in the capacitor. When the land design of printed wiring board is considered, it is necessary to set up the form and size of land pattern so that the amount of solder is suitable.



General, High-Voltage

(Unit: mm)

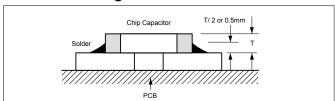
Size (EIA Code)	L×W	а	b	С
02 (01005)	0.4×0.2	0.13 to 0.20	0.12 to 0.18	0.20 to 0.23
03 (0201)	0.6×0.3	0.20 to 0.30	0.25 to 0.35	0.30 to 0.40
05 (0402)	1.0×0.5	0.30 to 0.50	0.35 to 0.45	0.40 to 0.60
105 (0603)	1.6×0.8	0.70 to 1.00	0.80 to 1.00	0.60 to 0.80
21 (0805)	2.0×1.25	1.00 to 1.30	1.00 to 1.20	0.80 to 1.10
316 (1206)	3.2×1.6	2.10 to 2.50	1.10 to 1.30	1.00 to 1.30
32 (1210)	3.2×2.5	2.10 to 2.50	1.10 to 1.30	1.90 to 2.30
42 (1808)	4.5×2.0	2.50 to 3.20 [*] 1	1.80 to 2.30	1.50 to 1.80
43 (1812)	4.5×3.2	2.50 to 3.20 [*] 1	1.80 to 2.30	2.60 to 3.00
52 (2208)	5.7×2.0	4.20 to 4.70	2.00 to 2.50	1.50 to 1.80
55 (2220)	5.7×5.0	4.20 to 4.70	2.00 to 2.50	4.20 to 4.70

 $^{^{*}\}mbox{1}$ Dimension of 3.0 to 3.5mm is recommended for "a", in the case of High-Voltage products.

Design of printed circuit and Soldering

The recommended fillet height shall be 1/2 of the thickness of capacitors or 0.5mm. When mounting two or more capacitors in the common land, it is necessary to separate the land with the solder resist strike so that it may become the exclusive land of each capacitor.

Ideal Solder Height



Item	Not recommended example	Recommended example/ Separated by solder
Multiple parts mount		Solder resist
Mount with leaded parts	Leaded parts	Solder resist Leaded parts
Wire soldering after mounting	Soldering iron Wire	Solder resist
Overview	Solder resist	Solder resist

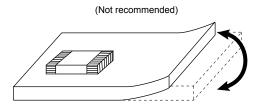
Multilayer Ceramic Chip Capacitors Surface Mounting Information

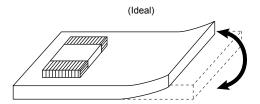


Mounting Design

The chip could crack if the PCB warps during processing after the chip has been soldered.

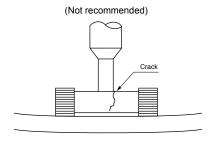
Recommended chip position on PCB to minimize stress from PCB warpage

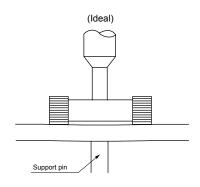




Actual Mounting

- 1) If the position of the vacuum nozzle is too low, a large force may be applied to the chip capacitor during mounting, resulting in cracking.
- 2) During mounting, set the nozzle pressure to a static load of 1 to 3 N.
- 3) To minimize the shock of the vaccum nozzle, provide a support pin on the back of the PCB to minimize PCB flexture.





4) Bottom position of pick up nozzle should be adjusted to the top surface of a substrate which camber is corrected.

Resin Mold

- 1) If a large amount of resin is used for molding the chip, cracks may occur due to contraction stress during curing. To avoid such cracks, use a low shrinkage resin.
- 2) The insulation resistance of the chip will degrade due to moisture absorption. Use a low moisture absorption resin.
- 3) Check carefully that the resin does not generate a decomposition gas or reaction gas during the curing process or during normal storage. Such gases may crack the chip capacitor or damage the device itself.

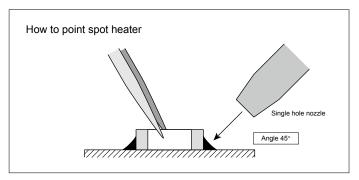
Multilayer Ceramic Chip Capacitors Surface Mounting Information

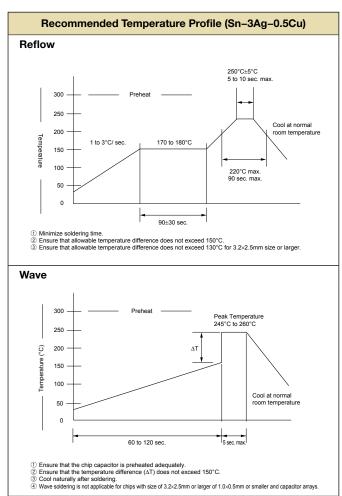


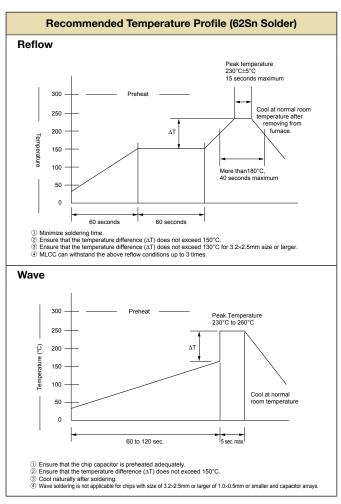
Soldering Method

- 1) Ceramic is easily damaged by rapid heating or cooling. If some heat shock is unavoidable, preheat enough to limit the temperature difference (Delta T) to within 150 degree Celsius.
- 2) The product size 1.6×0.8mm to 3.2×1.6mm can be used in reflow and wave soldering, and the product size of bigger than 3.2×1.6mm, or smaller than 1.6×0.8mm can be used in reflow.
 - Circuit shortage and smoking can be created by using capacitors which are used neglecting the above caution.
- 3) Please see our recommended soldering conditions.
- 4) In case of using Sn-Zn Solder, please contact us in advance.
- 5) The following condition is recommended for spot heater application.
- · Recommended spot heater condition

Item Condition	
Distance	5mm min.
Angle	45°
Projection Temp.	400°C max.
Flow rate	Set at the minimum
Nozzle diameter	2φ to 4φ (Single hole type)
Application time	10 sec. max. (1206 and smaller) 30 sec.max. (1210 and larger)







Soldering iron

1) Temperature of iron chip 1206 and smaller 350°C max.

1210 and larger 280°C max.

2) Wattage 80W max.

φ3.0mm max.

4) Soldering Time

3) Tip shape of soldering iron

3 sec. max.

5) Cautions

a) Pre-heating is necessary rapid heating must be avoided.

Delta T≤150°C (product size of bigger than 3.2×1.6mm. Delta T≤130°C)

- b) Avoid direct touching to capacitors.
- c) Avoid rapid cooling after soldering. Natural cooling is recommended.
- *Consult as if it is difficult to keep the temperature 280°C max. for 1210 and larger MLCC'S.

Multilayer Ceramic Chip Capacitors Precautions



Circuit Design

- 1. Once application and assembly environments have been checked, the capacitor may be used in conformance with the rating and performance which are provided in both the catalog and the specifications. Use exceeding that which is specified may result in inferior performance or cause a short, open, smoking, or flaming to occur, etc.
- 2. Please consult the manufacturer in advance when the capacitor is used in devices such as: devices which deal with human life, i.e. medical devices; devices which are highly public orientated; and devices which demand a high standard of liability.
 Accident or malfunction of devices such as medical devices, space equipment and devices having to do with atomic power could generate grave consequence with respect to human lives or, possibly, a portion of the public. Capacitors used in these devices may require high reliability design different from that of general purpose capacitors.
- 3. Please use the capacitors in conformance with the operating temperature provided in both the catalog and the specifications.

 Be especially cautious not to exceed the maximum temperature. In the situation the maximum temperature set forth in both the catalog and specifications is exceeded, the capacitor's insulation resistance may deteriorate, power may suddenly surge and short-circuit may occur.

 The capacitor has a loss, and may self-heat due to equivalent series resistance when alternating electric current is passed therethrough. As this effect becomes especially pronounced in high frequency circuits, please exercise caution.

 When using the capacitor in a (self-heating) circuit, please make sure the surface of the capacitor remains under the maximum temperature for usage. Also, please make certain temperature rises remain below 20°C.
- 4. Please keep voltage under the rated voltage which is applied to the capacitor. Also, please make certain the peak voltage remains below the rated voltage when AC voltage is super-imposed to the DC voltage.
 In the situation where AC or pulse voltage is employed, ensure average peak voltage does not exceed the rated voltage.
 Exceeding the rated voltage provided in both catalog and specifications may lead to defective withstanding voltage or, in worst case situations, may cause the capacitor to smoke or flame.
- 5. When the capacitor is to be employed in a circuit in which there is continuous application of a high frequency voltage or a steep pulse voltage, even though it is within the rated voltage, please inquire to the manufacturer.
 In the situation the capacitor is to be employed using a high frequency AC voltage or a extremely fast rising pulse voltage, even though it is within the rated voltage, it is possible capacitor reliability will deteriorate.
- 6. It is a common phenomenon of high-dielectric products to have a deteriorated amount of static electricity due to the application of DC voltage.

 Due caution is necessary as the degree of deterioration varies depending on the quality of capacitor materials, capacity, as well as the load voltage at the time of operation.
- 7. Do not use the capacitor in an environment where it might easily exceed the respective provisions concerning shock and vibration specified in the catalog and specifications.
 In addition, it is a common piezo phenomenon of high dielectric products to have some voltage due to vibration or to have noise due to voltage change. Please contact sales in such case.
- 8. If the electrostatic capacity value of the delivered capacitor is within the specified tolerance, please consider this when designing the respective product in order that the assembled product function appropriately.
- 9. Please contact us upon using conductive adhesives.

Storage

- 1. If the component is stored in minimal packaging (a heat-sealed or zippered plastic bag), the bag should be kept closed. Once the bag has been opened, reseal it or store it in a desiccator.
- 2. Keep storage place temperature +5 to +40 degree C, humidity 20 to 70% RH. See JIS C 60721-3-1, class 1K2 for other climatic conditions.
- 3. The storage atmosphere must be free of corrosive gas such as sulfur dioxide and chlorine. Also, avoid exposing the product to saline moisture. If the product is exposed to such atmospheres, the terminals will oxidize and solderability will be effected.
- 4. Precautions 1) to 3) apply to chip capacitors packaged in carrier tapes.
- 5. The solderability is assured for 6 months from our shipping date if the above storage precautions are followed.

Safety application guideline and detailed information of electrical properties are also provided in Kyocera home page; URL: http://www.kyocera.co.jp/electronic/